

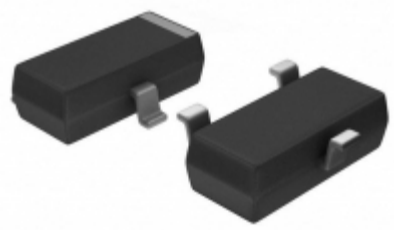


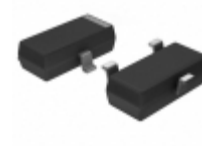
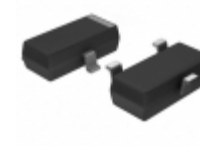

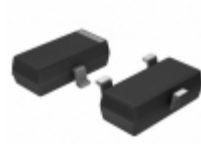

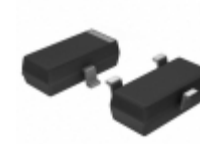
	<h2 style="color: red;">FJV4104RMTF</h2>
	<p>Hersteller-Teilenummer: FJV4104RMTF</p> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <p>Teil der Beschreibung: TRANS PREBIAS PNP 200MW SOT23-3</p> <p>Datenblätter:  1.FJV4104RMTF.pdf  2.FJV4104RMTF.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 131212 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	FJV4104RMTF
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	TRANS PREBIAS PNP 200MW SOT23-3
Kategorie	Diskrete Halbleiterprodukte > Transistoren-Bipolar
Teilstatus	131212 pcs Stock
detaillierte Beschreibung	Pre-Biased Bipolar Transistor (BJT) PNP - Pre-Biased
Serie	-
Befestigungsart	Surface Mount
Leistung - max	200mW
Verpackung / Gehäuse	TO-236-3, SC-59, SOT-23-3
Supplier Device-Gehäuse	SOT-23-3 (TO-236)
Transistor-Typ	PNP - Pre-Biased
Strom - Kollektor (Ic) (max)	100mA
Spannung - Kollektor-Emitter-Durchbruch (max)	50V
VCE Sättigung (Max) @ Ib, Ic	300mV @ 500µA, 10mA
Strom - Collector Cutoff (Max)	100nA (ICBO)
DC Stromgewinn (HFE) (Min) @ Ic, VCE	68 @ 5mA, 5V
Frequenz - Übergang	200MHz
Verpackung	Original-Reel®
Basisteilenummer	FJV4104
Widerstand - Basis (R1)	47 kOhms
Widerstand - Emitterbasis (R2)	47 kOhms
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)
Andere Namen	FJV4104RMTFDKR

FJV4104RMTF ist neu im Original, Suche FJV4104RMTF Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FJV4104RMTF AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage FJV4104RMTF: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FJV4103RMTF AMI Semiconductor / ON Semiconductor TRANS PREBIAS PNP 200MW SOT23-3</p>	 <p>FJV4102RMTF AMI Semiconductor / ON Semiconductor TRANS PREBIAS PNP 200MW SOT23-3</p>	 <p>FJV4103RMTF Fairchild/ON Semiconductor TRANS PREBIAS PNP 200MW SOT23-3</p>	 <p>FJV4106RMTF Fairchild/ON Semiconductor TRANS PREBIAS PNP 200MW SOT23-3</p>
 <p>FJV4102RMTF Fairchild/ON Semiconductor TRANS PREBIAS PNP 200MW SOT23-3</p>	 <p>FJV4104RMTF Fairchild/ON Semiconductor TRANS PREBIAS PNP 200MW SOT23-3</p>	 <p>FJV4102RLIMTF FAI FJV4102RLIMTF FAI</p>	 <p>FJV4105RMTF AMI Semiconductor / ON Semiconductor TRANS PREBIAS PNP 200MW SOT23-3</p>

heiße Teile

Mehr

 FJV3107RMTF	 FJV3108RMTF	 FJV3108RMTF	 FJV3109	 FJV3109RMTF
 FJV3109RMTF	 FJV3110RMTF	 FJV3110RMTF	 FJV3111RMTF	 FJV3111RMTF
 FJV3112RMTF	 FJV3112RMTF	 FJV3113RMTF	 FJV3113RMTF	 FJV3114RMTF
 FJV3114RMTF	 FJV3115RMTF	 FJV3115RMTF	 FJV4101RMTF	 FJV4101RMTF
 FJV4102RLIMTF	 FJV4102RMTF	 FJV4102RMTF	 FJV4103RMTF	 FJV4103RMTF
 FJV4104RMTF	 FJV4105RMTF	 FJV4105RMTF	 FJV4106RMTF	 FJV4106RMTF
 FJV4107RMTF	 FJV4107RMTF	 FJV4108RMTF	 FJV4108RMTF	 FJV4109RMTF
 FJV4109RMTF	 FJV4110RMTF	 FJV4110RMTF	 FJV4111RMTF	 FJV4111RMTF
 FJV4112RMTF	 FJV4112RMTF	 FJV4113RMTF	 FJV4113RMTF	 FJV4114RMTF
 FJV4114RMTF	 FJV42MTF	 FJV42MTF	 FJV992EMTF	 FJV992PMTF

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